TOSHIBA Transistor Silicon NPN Epitaxial Type

2SC3225

Switching Applications Solenoid Drive Applications

- High DC current gain: $h_{FE} = 500$ (min) (IC = 400 mA)
- Low collector-emitter saturation voltage: $V_{CE (sat)} = 0.5 \text{ V (max)}$ (IC = 300 mA)

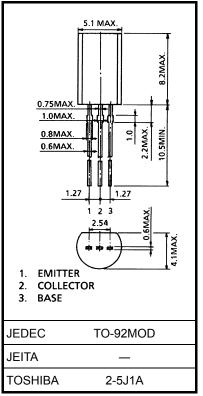
Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	40	V
Collector-emitter voltage	V _{CEO}	40	V
Emitter-base voltage	V _{EBO}	7	V
Collector current	IC	2	Α
Base current	ΙΒ	0.5	Α
Collector power dissipation	PC	900	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

Industrial Applications

Unit: mm



Weight: 0.36 g (typ.)

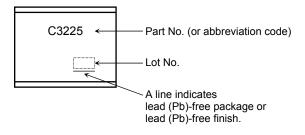
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

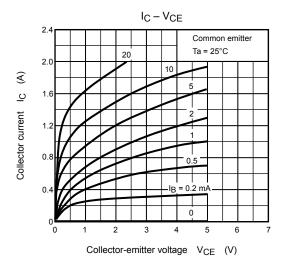
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

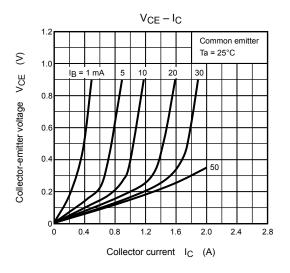
Electrical Characteristics (Ta = 25°C)

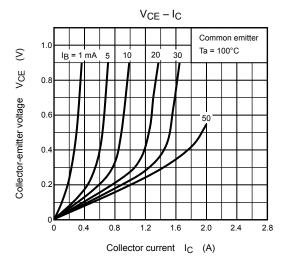
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	V _{CB} = 40 V, I _E = 0	_	_	10	μΑ
Emitter cut-off cur	rent	I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	1	μΑ
Collector-emitter b	oreakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	40	_	_	V
DC current gain		h _{FE}	V _{CE} = 1 V, I _C = 400 mA	500	_	_	
Collector-emitter s	saturation voltage	V _{CE} (sat)	I _C = 300 mA, I _B = 1 mA	_	0.3	0.5	V
Base-emitter satu	ration voltage	V _{BE} (sat)	I _C = 300 mA, I _B = 1 mA	_	_	1.1	V
Transition frequer	псу	f _T	V _{CB} = 2 V, I _C = 100 mA	_	220	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _B = 0, f = 1 MHz	_	20	_	pF
Switching time	Turn-on time	t _{on}	$20 \mu s$ Input $\frac{1}{1000}$	_	1.0	_	
	Storage time	t _{stg}		_	3.0	_	μs
	Fall time	t _f		_	1.2	_	

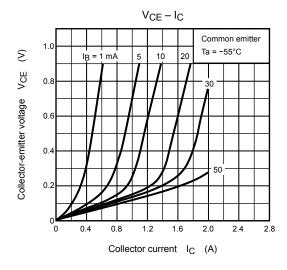
Marking

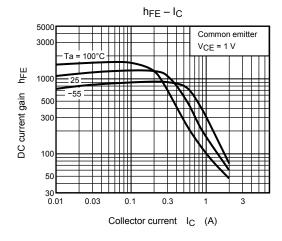


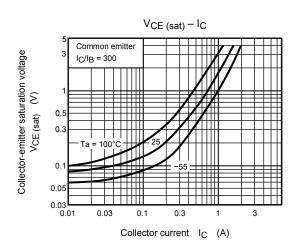


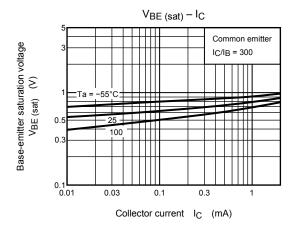


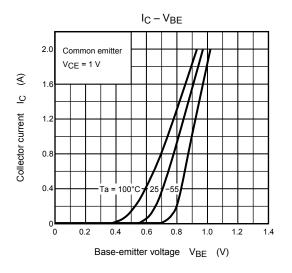


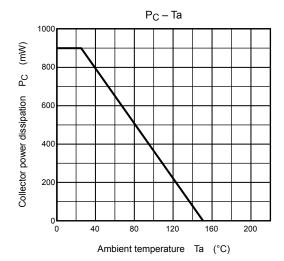


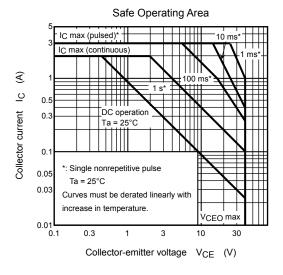












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